Low-Power, Two-Port, High-Speed, USB2.0 (480Mbps) DPDT Analog Switch BL1530

Description

The BL1530 is a Low-Power, Two-Port, High-Speed, USB2.0 (480Mbps) double –pole double-throw (DPDT) Analog Switch featuring an On-Resistance of 4.5 ohm at VCC=3V and a Low On Capacitance 3.7pf Typical.

The BL1530 is compatible with the requirements of USB2.0 and the wide bandwidth needed to pass the third harmonic, resulting in signals with minimum edge and phase distortion. Superior channel-to channel crosstalk also minimizes interference. Break-before-make function for both parts eliminates signal disruption during switching from preventing both switches being enabled simultaneously. The BL1530 contains special circuitry on the switch I/O pins for applications where the VCC supply is powered-off (VCC=0), which allows the device to withstand an over-voltage condition. This device is designed to minimize current consumption even when the control voltage applied to the Sel pin is lower than the supply voltage (VCC). This feature is especially valuable to ultra-portable applications, such as cell phones, allowing for direct interface with the general purpose I/Os of the baseband processor. Other applications include switching and connector sharing in portable cell phones, PDAs, digital cameras, printers, and notebook computers.

Pin Configuration



Features

- Wide Power Supply Range: 2.3V to 5V
- Low On Capacitance 3.7pf Typical
- Low On Resistance 4.5 Ω (typ) at 3V VDD when V_{SW}=0.4V
- High Bandwidth (-3db): >720MHz without C_L and >550MHz with C_L =5pF
- Low Power Consumption: 1uA Maximum
- ESD: pass 8kV HBM test
- Over voltage tolerance (OVT) on all USB ports up to 5.25V without external components
- TTL/CMOS Compatible
- Break-Before-Make Switching
- Operation Temperature Range: -40°C to 85°C
- UTQFN1.8×1.4-10L and MSOP10L Package

Applications

Cell phone, PDAs, Digital camera, Notebook, LCD Monitor, TV, SET-TOP BOX

Block Diagram



Function Table

OEb	Sel	Function
1	Х	Disconnect
0	0	Dp, Dn=Dp1, Dn1
0	1	Dp, Dn=Dp2, Dn2

BL1530—DPDT USB2.0 Analog Switch

Pin Description

PIN num		Pin Name	Туре	Description	
UTQFN10L	MSOP10L		Турс	Description	
1	2	Dp1	Input/Output	Data Port	
2	3	Dp2	Input/Output	Data Port	
3	4	Dp	Input/Output	USB Data BUS	
4	5	GND	Ground	Ground	
5	6	Dn	Input/Output	USB Data BUS	
6	7	Dn2	Input/Output	Data Port	
7	8	Dn1	Input/Output	Data Port	
8	9	OEb	Input	Switch enable	
9	10	VCC	PWR	Power Supply	
10	1	Sel	Input	Switch select	

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Min	Max	Units
DC Supply Voltage	VCC	-0.5	5.5	V
DC Switch Voltage	Dpn / Dnn / Dp / Dn	-0.5	VCC+ 0.3	V
DC Input Voltage	V_{Oeb} / V_{Sel}	-0.5	VCC	V
Continuous Current	I _(Dpn/Dnn/Dp/Dn)	-50	+50	mA
Peak Current ⁽¹⁾	I _{PEAK(Dpn/Dnn/Dp/Dn)}	-100	+100	mA
Operating Temperature Range	T _A	-40	85	°C

Notes:

(1) Pulsed at 1ms, 50% duty circle

(2) Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device. These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ORDERING INFORMATION

MODEL	PIN- PACKAGE	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ACKAGE OPTION
BL1530TQFN	UTQFN1.8×1.4- 10L	- 40 °C to +85 °C	IYW ⁽¹⁾	Tape and Reel, 3000
BL1530MSOP	MSOP10L	- 40 °C to +85 °C	I1G YWW	Tape and Reel, 3000

WHERE(1):

"IYW" IS 3 DIGITS PRODUCTION ID COLOUR: LASER MARKING

"I" stands for the product BL1530.

"Y"stands for the product year, for example, "1" stands for the year 2011.

"W" stands for the product week, for example, "a" stands for the first week, "A" stands for the 27th week.

BL1530—DPDT USB2.0 Analog Switch

DC ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Conditions	Gua	ranteed	Limit	Unit
rarameter	Symbol	Conditions		. Typ. ⁽¹⁾	Max.	Umt
Analog Switch						
Analog Signal Range	$V_{Pn}\!/V_{Nn}\!/V_p\!/V_n$		0		VCC	V
On-Resistance ⁽²⁾	R _{ON}	$VCC = 3V, V_{SW} = 0.4V,$ $I_{ON} = -8mA$		4.5		Ω
On-Resistance Match Between Channels ⁽³⁾	ΔR_{ON}	$VCC = 3V, V_{SW} = 0.4V,$ $I_{ON} = -8mA$		0.1		Ω
Current				•		
Source Off Leakage Current	$I_{Pn/Nn\;(OFF)}$	VCC=3.6V, V_p/V_n = 3.6/0.3V, V_{Pn}/V_{Nn} =0.3/3.6V	-1		1	uA
Channel on Leakage Current	$I_{Pn/Nn(ON)}$	VCC=3.6V, V_p/V_n = 3.6/0.3V, V_{Pn}/V_{Nn} =3.6/0.3V	-1		1	uA
POWER OFF leakage current	I_{OFF}	VCC = $0V, V_{SW}=0V$ to 3.6V, Vcontrol=0 or VCC	-1		1	uA
Quiescent supply current	I _{CC}	VCC=3V, Vcontrol=0 or VCC, Iout=0			1	uA
Increase in I_{CC} current per control voltage and VCC	I _{CCT}	VCC=3.6V, Vcontrol=2.6V			4	uA
Input Leakage Current	$I_{OEb/Sel}$	$V_{OEb / Sel} = 0$ or VCC			1	uA
Digital I/O		1	1	<u> </u>		
Input Voltage High	V _{IH}	VCC = 3.0-3.6V	1.6			V
Input Voltage Low	V _{IL}	VCC = 3.0-3.6V			0.5	V

Note:

- (1) Typical characteristics are at +25 $^{\circ}$ C
- (2) Measured by the voltage drop between Dpn/Dnn and Dp/Dn pins at the indicated current through the switch. On resistance is determined by the lower of the voltage on the two (Dpn/Dnn and Dp/Dn ports).
- (3) Δ $R_{\text{ON}} {=}$ $R_{\text{ON}(\text{MAX})} {-}$ $R_{\text{ON}(\text{MIN})},$ between Dp and Dn .

DYNAMIC CHARACTERISTICS

Parameter	Shal	Conditions	Guaranteed Limit			Unit
rarameter	Symbol	Conditions	Min.	Typ. ⁽¹⁾	Max.	Umt
DRIVER CHARACTER	ISTICS					8
Turn-On Time	4	VCC=3.3V, R _L =500mh,		10	30	ns
Tum-On Time	t _{ON}	C _L =5pF, V _{SW} =0.8V				
Turn-Off Time	t	VCC=3.3V, R _L =500mh,		20	25	ns
	t _{OFF}	C _L =5pF,V _{SW} =0.8V				
Break-Before-Make Time	+	VCC=3.3V, R _L =500mh,	2.0	3	6.5	ns
Dieak-Deloie-Make Time	t _{BBM}	$C_L = 5pF, V_{SW1,2} = 0.8V$	2.0			
Propagation Dalay	t	VCC=3.3V, R _L =500mh,		0.2		ns
Propagation Dalay	t _{PD}	C _L =5pF				
CAPACITANCE						
Control Capacitance	C _{IN}	VCC=0V		1.5		pF
ON Capacitance	C _{ON}	VCC = 3.3V,OE=0V,		3.7		pF
orveupuertunee		f=240MHz				P*
OFF Capacitance	C _{OFF}	VCC = 3.3V, OE = 3.3V,		2.0		pF
-		f=240MHz				1
APPLICATION CHAR	ACTERI	STICS				-
3dB Bandwidth	farr	$VCC = 3.3V, R_L = 500mh, C_L = 0pF$	7	720		MHz
	f _{3dB}	$VCC = 3.3V, R_L = 500mh, C_L = 5pF$	7	550		MHz
Off Isolation ⁽²⁾	V _{Iso}	VCC = 3.3V,		-30		dB
		R _L =500mh,f=250MHz		-30	, v	
Channel crosstalk	XTALK	VCC = 3.3V,		-35		dB
		R _L =500mh,f=250MHz				

Note:

- (1) Typical characteristics are at 25 $^{\rm C}$
- (2) Off Channel Isolation = $20\log_{10} [(V_{P1 \setminus P2})/V_P]$ or $20\log_{10} [(V_{N1 \setminus N2})/V_N]$

TEST SETUP CIRCUITS







Figure 2. Test Circuit for Bandwidth



Figure3. Test Circuit for Off Isolation









Test Circuit 5. Test Circuit for Switch Times



Test Circuit 5. Test Circuit for Break-Before-Make Time Delay, t_{BBM}





APPLICATION NOTE

Meeting USB 2.0 V_{BUS} Short Requirements

(1) Power-Off Protection

For a V_{BUS} short circuit the switch is expected to withstand such a condition for at least 24 hours. The BL1530 has the specially designed circuit which prevents unintended signal bleed through as well as guaranteed system reliability during a power-down, over-voltage condition. The protection has been added to the common pins (Dp, Dn).

(2) Power-On Protection

The USB 2.0 specification also notes that the USB device should be capable of withstanding a V_{BUS} short during transmission of data. This modification works by limiting current flow back into the VCC rail during the over-voltage event so current remains within the safe operating range.

PACKAGE OUTLINE DIMENSIONS (UTQFN1.8×1.4-10L)

UTQFN1.8×1.4-10L



NOTE: All linear dimensions are in millimeters.

MSOP10L



SYMBOL	MILLIMETER			
SIMBOL	MIN	NOM	MAX	
А			1.10	
A1	0.05	_	0.15	
A2	0.75	0.85	0.95	
A3	0.30	0.35	0.40	
ъ	0.19		0.28	
b 1	0.18	0.20	0.23	
c	0.15	_	0.20	
c 1	0.14	0.152	0.16	
D	2.90	3.00	3.10	
Е	4.70	4.90	5.10	
E1	2.90	3.00	3.10	
е	0.50BSC			
L	0.40	_	0.70	
L1	0.95BSC			
θ	0	_	8	
L/P載体尺寸 (mil)	71#96			